



DMN5L06VKQ

## **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	2Ω @ V <sub>GS</sub> = 5V	280mA
50V	2.5Ω @ V <sub>GS</sub> = 2.5V	258mA
	3Ω @ V <sub>GS</sub> = 1.8V	235mA

## Description

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

General Purpose Interfacing Switch





Top View

#### DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

#### Features

- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN5L06VKQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)



Internal Schematic

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN5L06VKQ-7	SOT563	3,000/Tape & Reel
DMN5L06VKQ-13	SOT563	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### Marking Information (Note 5)

Date Code Key		D <sub>2</sub> G <sub>1</sub> KAB S <sub>2</sub> G <sub>2</sub>	YM		YM = Y = Y	= Product = Date Coc Year (ex: G Month (ex:	le Marking 6 = 2019)	1				
Year	2019	2020	20	)21	2022	2023	3	2024	2025	202	26	2027
Code	G	Н			J	K		L	М	N		0
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Note: 5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).



## Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain Source Voltage		V <sub>DSS</sub>	50	V
Drain-Gate Voltage $R_{GS} \le 1.0m\Omega$		V <sub>DGR</sub>	50	V
Gate-Source Voltage	Continuous	Vgss	±20	N/
	Pulsed		±40	v
Drain Current (Note 6) Continuous Pulsed		lD	280	mA
		Ідм	1.5	А

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	PD	250	mW
Thermal Resistance, Junction to Ambient (Note 6)	Reja	500	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	O°

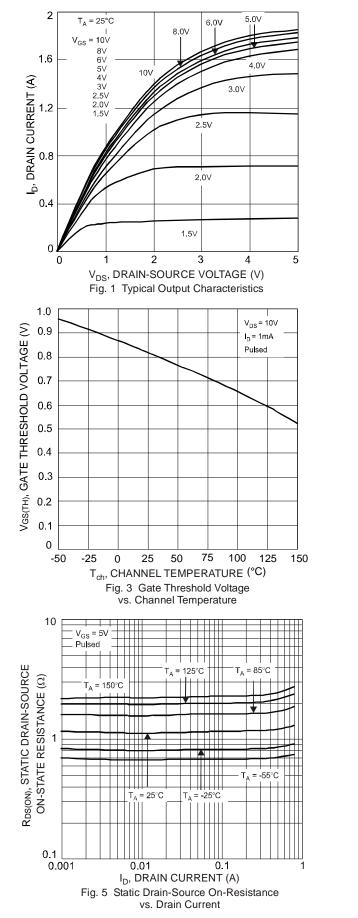
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

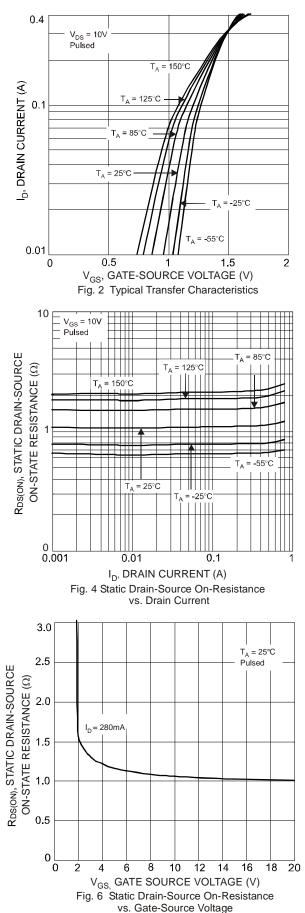
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	.,		71				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	50	_	_	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current @ $T_C = +25^{\circ}C$	I <sub>DSS</sub>	_	_	60	nA	$V_{DS} = 50V, V_{GS} = 0V$	
				1	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
Gate-Body Leakage	lgss	_	_	500	nA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
				50	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage @T <sub>J</sub> = +25°C	\/	0.49		1.0	v		
@T <sub>J</sub> = 0°C to +85°C (Note 8)	Vgs(th)	0.30		1.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		— 2.49	2.49	3.0		$V_{GS} = 1.8V, I_D = 50mA$	
Static Drain-Source On-Resistance	RDS(ON)	RDS(ON)	_	1.53	2.5	Ω	Vgs = 2.5V, ID = 50mA
		—	1.16	2.0		Vgs = 5.0V, ID = 50mA	
On-State Drain Current	ID(ON)	0.5	1.4	—	А	Vgs = 10V, Vds = 7.5V	
Forward Transconductance	Y <sub>fs</sub>	200	—	—	ms	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.2A	
Source-Drain Diode Forward Voltage	Vsd	0.5	0.73	1.4	V	Vgs = 0V, Is = 115mA	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance Output Capacitance		_	-	50	pF		
		_	_	25	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	—	5.0	pF		

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

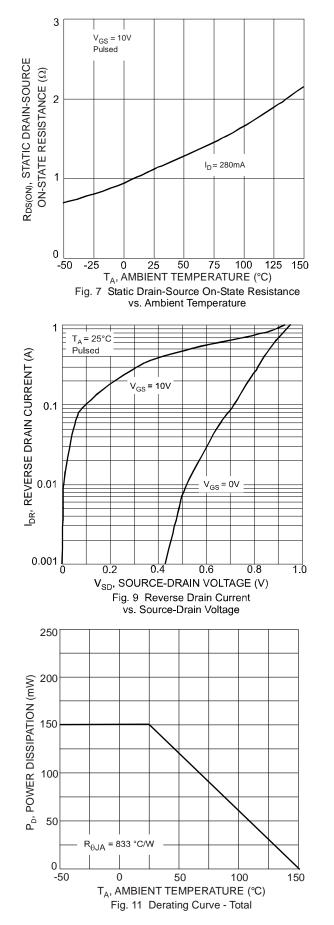


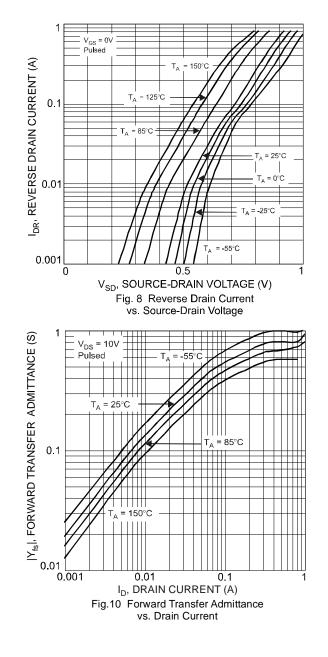
# DMN5L06VKQ







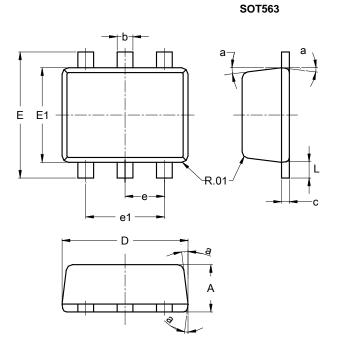






## **Package Outline Dimensions**

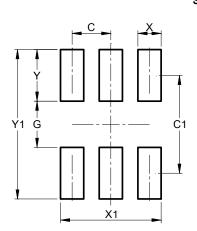
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563							
Dim	Min	Max	Тур				
Α	0.55	0.60	0.60				
b	0.15	0.30	0.20				
С	0.10	0.18	0.11				
D	1.50	1.70	1.60				
Е	1.55	1.70	1.60				
E1	1.10	1.25	1.20				
е			0.50				
e1	0.90	1.10	1.00				
L	0.10	0.30	0.20				
а	8°	9°	7°				
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563

Dimensions	SOT563
С	0.500
C1	1.270
G	0.600
Х	0.300
X1	1.300
Y	0.670
Y1	1.940



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